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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO	
10/074,722	02/11/2002	Christophe F. Pomarede	ASMEX.320 A	6768	
20995	7590 12/04/2003		EXAM	EXAMINER	
KNOBBE M 2040 MAIN S	ARTENS OLSON & TREET	POMPEY, RON EVERETT			
FOURTEENT	H FLOOR		ART UNIT	PAPER NUMBER	
IRVINE, CA	92614		2812	*****	

DATE MAILED: 12/04/2003

Please find below and/or attached an Office communication concerning this application or proceeding.

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		Application No.	Applicant(s)	WN	
		10/074,722	POMAREDE ET	POMAREDE ET AL.	
	Office Action Summary	Examin r	Art Unit		
		Ron E Pompey	2812		
Period fo	The MAILING DATE of this communicati r Reply	on appears on the cover shee	et with the correspondence ac	Idress	
THE N - Exten after S - If the - If NO - Failur - Any re	DRTENED STATUTORY PERIOD FOR MAILING DATE OF THIS COMMUNICAT sions of time may be available under the provisions of 37 SIX (6) MONTHS from the mailing date of this communical period for reply specified above is less than thirty (30) day period for reply is specified above, the maximum statutory e to reply within the set or extended period for reply will, beyly received by the Office later than three months after the dipatent term adjustment. See 37 CFR 1.704(b).	FION. CFR 1.136(a). In no event, however, manual tion. It is a reply within the statutory minimum or a period will apply and will expire SIX (6) by statute, cause the application to become	ay a reply be timely filed of thirty (30) days will be considered timel MONTHS from the mailing date of this c	ly. ommunication	
1)	Responsive to communication(s) filed or	n 24 September 2003.			
		This action is non-final.			
3)	Since this application is in condition for a closed in accordance with the practice u	allowance except for formal r	matters, prosecution as to the C.D. 11, 453 O.G. 213.	e merits is	
	on of Claims		,		
5)	Claim(s) <u>1-47</u> is/are pending in the applicate of the above claim(s) is/are wellaim(s) is/are wellaim(s) is/are allowed. Claim(s) <u>1-47</u> is/are rejected. Claim(s) is/are objected to. Claim(s) are subject to restriction	ithdrawn from consideration.			
	on Papers	and a constant of an one of the			
9)□ T	he specification is objected to by the Ex	aminer.			
10)∐ Т	The drawing(s) filed on is/are: a)	☐ accepted or b)☐ objected	to by the Examiner.		
	Applicant may not request that any objection				
	Replacement drawing sheet(s) including the			` '	
	The oath or declaration is objected to by	the Examiner. Note the attac	ched Office Action or form PT	O-152.	
	nder 35 U.S.C. §§ 119 and 120				
a)	Acknowledgment is made of a claim for f All b) Some * c) None of: 1. Certified copies of the priority docu 2. Certified copies of the priority docu 3. Copies of the certified copies of the application from the International E ee the attached detailed Office action for cknowledgment is made of a claim for do ice a specific reference was included in t CFR 1.78. The translation of the foreign language	uments have been received. uments have been received i e priority documents have be Bureau (PCT Rule 17.2(a)). a list of the certified copies re mestic priority under 35 U.S the first sentence of the spec	n Application No een received in this National not receivedC. § 119(e) (to a provisional ification or in an Application	application)	
14)□ Ac	cknowledgment is made of a claim for do erence was included in the first sentence	mestic priority under 35 U.S.	.C. §§ 120 and/or 121 since	a specific CFR 1.78.	
Attachment(:	c)				
1) Notice 2) Notice	of References Cited (PTO-892) of Draftsperson's Patent Drawing Review (PTO-94 ation Disclosure Statement(s) (PTO-1449) Paper N	18) 5) Notice	ew Summary (PTO-413) Paper No(s of Informal Patent Application (PTO		
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DETAILED ACTION

Claim Rejections - 35 USC § 103

- 1. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
 - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 2. Claims 1-47 are rejected under 35 U.S.C. 103(a) as being unpatentable over Murthy et al. (US 6,373,112) in further view of Nakabayashi et al. (US 6,319782) and Shiota et al. (US 5,879,970).

Murthy discloses the limitations of claims 1-47:

depositing a silicon-containing seed layer (106, fig. 2) over the high dielectric constant material (104, fig. 2) under seed phase conditions (col. 2, Ins. 29-38); and depositing a silicon-containing bulk layer (108, fig. 2) over the seed layer under bulk phase conditions, the bulk phase conditions selected to result in a higher deposition rate than the seed phase conditions (col. 4, In. 41 – col., In. 9).

3. Murthy discloses the claimed limitations, as described above, except the limitations disclosed below by Nakabayashi and Shiota:

Nakabayashi discloses:

wherein silane includes higher order silane gas;

wherein the seed phase is less than 500 Å/min and the deposition rate for of the bulk phase is greater than 500 Å/min (col. 10, ln. 44 - col. 11, ln. 31);

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Shiota discloses:

using a non-hydrogen carrier gas (col. 1, Ins. 20-40); and

Therefore one of ordinary skill would have combined the limitations disclosed in Nakabayashi and Shiota with Murthy, because Murthy does not explicitly state some of the process conditions that are claimed. Also, Murthy explicitly discloses "other oxides such as for example Hafnium oxides, and the specification does not disclose a distinctive difference between the materials listed in the group of high dielectric materials. Therefore, because Murthy does disclose one in the group it would have been obvious to one of ordinary skill in the art at the time of the invention to use the other materials in the group.

Response to Arguments

4. Applicant's arguments filed 9-24-03, pertaining to claims 1-47, have been fully considered but they are not persuasive.

Applicant(s) argues that neither the 0 nor Shiota reference disclose using a non-hydrogen carrier. However in Nakabayashi (col. 10, Ins. 44-47; 51-55) discloses using Chlorine as a carrier gas, to strip away unwanted oxide that is formed. This is one example that is shown in the Nakabayashi or Shiota references that demonstrate one of ordinary skill in the art uses non-hydrogen gases in the formation of a silicon layer.

Also, Applicant argues that Nakabayashi does not show motivation to use disilane instead of the silane disclosed in Murthy. Murthy talks of the general conditions of how to form a seed layer and give an example of using silane as the main gas.

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Nakabayashi, discloses using either silane or disilane (col. 10, lns. 60-65), therefore showing that one of ordinary skill in the art uses the gases interchangeably.

Conclusion

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5. **THIS ACTION IS MADE FINAL.** Applicant is reminded of the extension of time

policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later

Any inquiry concerning this communication or earlier communications from the examiner should be directed to Ron E Pompey whose telephone number is (571) 272-1680. The fax phone number for the organization where this application or proceeding is assigned is (703) 305-3432.

than SIX MONTHS from the mailing date of this final action.

Ron Pompey Art Unit: 2812

December 1, 2003

John F. Niebling Supervisory Patent Examiner Technology Center 2800